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2.5 Gbps / 5.0 Gbps 4 Lane PCI Express Repeater with **Equalization and De-Emphasis**

General Description

The DS50PCI402 is a low power, 4 lane bidirectional buffer/ equalizer designed specifically for PCI Express Gen1 and Gen2 applications. The device performs both receive equalization and transmit de-emphasis, allowing maximum flexibility of physical placement within a system. The receiver is capable of opening an input eve that is completely closed due to inter-symbol interference (ISI) induced by the interconnect medium.

The transmitter de-emphasis level can be set by the user depending on the distance from the DS50PCI402 to the PCI Express endpoint. The DS50PCI402 contains PCI Express specific functions such as Transmit Idle, RX Detection, and Beacon signal pass through.

The device provides automatic receive detection circuitry which controls the input termination impedance. By automatically reflecting the current load impedance seen on the outputs back to the corresponding inputs the DS50PCI402 becomes completely transparent to both the PCIe root complex and endpoint. An internal rate detection circuit is included to detect if an incoming data stream is at Gen2 data rates, and adjusts the de-emphasis on it's output accordingly. The signal conditioning provided by the device allows systems to upgrade from Gen1 data rates to Gen2 without reducing their physical reach. This is true for FR4 applications such as backplanes, as well as cable interconnect.

Features

- Input and Output signal conditioning increases PCIe reach in backplanes and cables
- 0.09 UI of residual deterministic iitter at 5Gbps after 42" of FR4 (with Input EQ)
- 0.11 UI of residual deterministic jitter at 5Gbps after 7m of PCIe Cable (with Input EQ)
- 0.09 UI of residual deterministic jitter at 5Gbps with 28" of FR4 (with Output DE)
- 0.13 UI of residual deterministic jitter at 5Gbps with 7m of PCIe Cable (with Output DE)
- Adjustable Transmit VOD 800 to 1200mVp-p
- Automatic and manual Receiver Detection and input termination control circuitry
- Automatic power management on an individual lane basis via SMBus
- Adjustable electrical idle detect threshold.
- Data rate optimized 3-stage equalization to 27 dB gain
- Data rate optimized 6-level 0 to 12 dB transmit deemphasis
- Flow-thru pinout in 10mmx5.5mm 54-pin leadless LLP package
- Single supply operation at 2.5V
- >6kV HBM ESD rating
- -10 to 85°C operating temperature range



e-Emphasis

Block Diagram - Detail View Of Channel (1 of 8)



30107386



Note 1: The center DAP on the package bottom is the device GND connection. This pad must be connected to GND through multiple (minimum of 8) vias to ensure optimal electrical and thermal performance.

Ordering Information

Pin Diagram

NSID	Qty	Spec	Package
DS50PCI402SQ	Tape & Reel Supplied As 2,000 Units	NOPB	SQA54A
DS50PCI402SQE	Tape & Reel Supplied As 250 Units	NOPB	SQA54A

Pin Descriptions

Pin Name	Pin Number	I/O, Type	Pin Description
Differential High Spee	ed I/O's	•	
IA_0+, IA_0- ,	10, 11	I, CML	Inverting and non-inverting CML differential inputs to the
IA_1+, IA_1-,	12, 13		equalizer. A gated on-chip 50Ω termination resistor connects
IA_2+, IA_2-,	15, 16		INA_0+ to VDD and INA_0- to VDD when enabled.
IA_3+, IA_3-	17, 18		
OA_0+, OA_0-,	35, 34	O,LPDS	Inverting and non-inverting low power differential signal
OA_1+, OA_1-,	33, 32		(LPDS) 50 Ω driver outputs with de-emphasis. Compatible
OA_2+, OA_2-,	31, 30		with AC coupled CML inputs.
OA_3+, OA_3-	29, 28		
IB_0+, IB_0- ,	45, 44	I, CML	Inverting and non-inverting CML differential inputs to the
IB_1+, IB_1-,	43, 42		equalizer. A gated on-chip 50Ω termination resistor connects
IB_2+, IB_2-,	40, 39		INB_0+ to VDD and INB_0- to VDD when enabled.
IB_3+, IB_3-	38, 37		
OB_0+, OB_0-,	1, 2	O,LPDS	Inverting and non-inverting low power differential signal
OB_1+, OB_1-,	3, 4		(LPDS) 50 Ω driver outputs with de-emphasis. Compatible
OB_2+, OB_2-,	5,6		with AC coupled CML inputs.
OB_3+, OB_3-	7,8		
Control Pins — Share	ed (LVCMOS)	1	
ENSMB	48	I, LVCMOS w/	System Management Bus (SMBus) enable pin.
		internal	When pulled high provide access internal digital registers that
		pulldown	are a means of auxiliary control for such functions as
			equalization, de-emphasis, vOD, rate, and idle detection
			When pulled low access to the SMBus registers are disabled
			and SMBus function nins are used to control the Equalizer
			and De-Emphasis.
			Please refer to "SMBus configuration Registers" section and
			Electrical Characteristics - Serial Management Bus Interface
			for detail information.
ENSMB = 1 (SMBUS N	MODE)		
SCL	50	I, LVCMOS	ENSMB = 1
			SMBUS clock input pin is enabled. External pull-up resistor
			maybe needed. Refer to R _{TERM} in the SMBus specification.
SDA	49	I, LVCMOS,	ENSMB = 1
		O, Open	The SMBus bi-directional SDA pin is enabled. Data input or
		Drain	open drain output. External pull-up resistor is required.
			Refer to R _{TERM} in the SMBus specification.
AD0-AD3	54, 53, 47, 46	I, LVCMOS w/	ENSMB = 1
		internal	SMBus Slave Address Inputs. In SMBus mode, these pins are
		pulldown	the user set SMBus slave address inputs. See section —
			System Management Bus (SMBus) and Configuration
			Registers for additional information.
ENSMB = 0 (NORMAL	PIN MODE)		
EQA0, EQA1	20, 19	I,FLOAT,	EQA/B ,0/1 controls the level of equalization of the A/B sides
EQB0, EQB1	46, 47	LVCMOS	as shown in . The EQA/B pins are active only when ENSMB
			is de-asserted (Low). Each of the 4 A/B channels have the
			same level unless controlled by the SMBus control registers.
			When ENSMB goes high the SMBus registers provide
			Independent control of each lane, and the EQB0/B1 pins are
			converted to SIVIBUS AD2/AD3 inputs.

Pin Name	Pin Number	I/O, Type	Pin Description
DEMA0, DEMA1 DEMB0, DEMB1	49, 50 53, 54	I,FLOAT, LVCMOS	DEMA/B ,0/1 controls the level of de-emphasis of the A/B sides as shown in . The DEMA/B pins are only active when ENSMB is de-asserted (Low). Each of the 4 A/B channels have the same level unless controlled by the SMBus control registers. When ENSMB goes High the SMBus registers provide independent control of each lane and the DEM pins are converted to SMBUS AD0/AD1 and SCL/SDA inputs.
RATE	21	I,FLOAT, LVCMOS	RATE control pin controls the pulse width of de-emphasis of the output. A Low forces Gen1 (2.5Gbps), High forces Gen 2 (5Gbps), Open/Floating the rate is internally detected after each exit from idle and the pulse width is set appropriately. When ENSMBUS= 1 this pin is disabled and the RATE function is controlled internally by the SMBUS registers. Refer to .
Control Pins — Both	Modes (LVCM	OS)	
RXDETA,RXDETB	22,23	I, LVCMOS w/ internal pulldown	The RXDET pins in combination with the ENRXDET pin controls the receiver detect function. Depending on the input level, a 50Ω or $>50K\Omega$ termination to the power rail is enabled. Refer to .
PRSNT	52	I, LVCMOS	Cable Present Detect input. High when a cable is not present per PCIe Cabling Spec. 1.0. Puts part into low power mode. When low (normal operation) part is enabled.
ENRXDET	26	I, LVCMOS w/ internal pulldown	Enables pin control of receiver detect function. The default is automatic RXDET using the internal pulldown. Pin must be pulled high for manual RXDETA/B operation. Controls individual A and B sides. Refer to .
TXIDLEA,TXIDLEB	24,25	I, FLOAT, LVCMOS	Controls the electrical idle function on corresponding outputs when enabled. H= electrical Idle, Float=autodetect (Idle on input passed to output), L=Idle squelch disabled as shown in <i>Table 5</i> .
Analog	2	2	
SD_TH	27	I, ANALOG	Threshold select pin for electrical idle detect threshold. Float pin for default 130mV DIFF p-p, otherwise connect resistor from SD_TH to GND to set threshold voltage as shown in <i>Table 6</i> .
Power			
VDD	9, 14,36, 41, 51	Power	Power supply pins CML/analog.
GND	DAP	Power	Ground pad (DAP - die attach pad).
Notes: FLOAT = 3rd input sta	ate, don't drive p	in. Pin is interna	ally biased to mid level with 50 k Ω pull-up/pull-down. If high Z

output not available, drive input to VDD/2 to assert mid level state.

Internal pulldown = Internal 30 k Ω pull-down resistor to GND is present on the input.

LVCMOS inputs without the "Float" conditions must be driven to a logic Low or High at all times or operation is not guaranteed.

Input edge rate for LVCMOS/FLOAT inputs must be faster than 50 ns from 10–90%.

Functional Description

The DS50PCI402 is a low power media compensation 4 lane repeater optimized for PCI Express Gen 1 and Gen 2 media including lossy FR-4 printed circuit board backplanes and balanced cables. The DS50PCI402 operates in two modes: Pin Control Mode (ENSMB = 0) and SMBus Mode (ENSMB = 1).

Pin Control Mode:

When in pin mode (ENSMB = 0), the repeater is configurable with external pins. Equalization and de-emphasis can be selected via pin for each side independently. When de-emphasis is asserted VOD is automatically increased per the De-Emphasis table below for improved performance over lossy media. The receiver detect pins RXDETA/B provide manual control for input termination (50 Ω or >50K Ω). Rate optimization is also pin controllable, with pin selections for 2.5Gbps, 5Gbps, and auto detect. The receiver electrical idle detect threshold is also programmable via an optional external resistor on the SD_TH pin.

SMBUS Mode:

When in SMBus mode the equalization, de-emphasis, and termination disable features are all programmable on a indi-

vidual lane basis, instead of grouped by sides as in the pin mode case. Upon assertion of ENSMB the RATE, EQx and DEMx functions revert to register control immediately. The EQx and DEMx pins are converted to AD0-AD3 SMBus address inputs. The other external control pins remain active unless their respective registers are written to and the appropriate override bit is set, in which case they are ignored until ENSMB is driven low. On powerup and when ENSMB is driven low all registers are reset to their default state. If PRSNT is asserted while ENSMB is high, the registers retain their current state.

Equalization settings accessible via the pin controls were chosen to meet the needs of most PCIe applications. If additional fine tuning or adjustment is needed, additional equalization settings can be accessed via the SMBus registers. Each input has a total of 24 possible equalization settings. The tables show a typical gain for each gain stage (GST[1:0]) and boost level (BST[2:0]) combination. When using SMBus mode, the Equalization and De-Emphasis levels are set using registers.

		EQ S	etting	EQ Ga	in (dB)	
EQ1	EQ0	GST	BST	1.25 GHz	2.5 GHz	Suggested Use
		[1:0]	[2:0]			
F	F	00	000	0	0	Bypass - Default Setting
		01	000	1.6	3.2	
		01	001	2.1	4.2	
1	1	01	010	2.6	5.0	8" FR4 (6-mil trace) or < 1m (28 AWG) PCIe cable
		01	011	3.2	5.9	
		01	100	4.0	7.3	
		01	101	4.9	7.9	
		01	110	5.4	8.5	
		01	111	5.6	9.0	
	F=	=Float (o	don't driv	e pin, each float	t pin has an inte	rnal 50K Ohm resistor to VDD and GND), 1=High, 0=Low

TABLE 1. Equalization Settings with GST=1 for Pins or SMBus Registers

TABLE 2. Equalization Settings with GST=2 for Pins or SMBus Registers

		EQ S	etting	EQ Ga	in (dB)				
EQ1	EQ0	GST	BST	1.25 GHz	2.5 GHz	Suggested Use			
		[1:0]	[2:0]						
0	0	10	000	3.8	7.6	14" FR4 (6-mil trace) or 1m (28 AWG) PCIe cable			
		10	001	5.1	9.9				
F	0	10	010	6.4	11.6	20" FR4 (6-mil trace) or 5m (26 AWG) PCIe cable			
		10	011	7.6	13.5				
		10	100	9.5	16.1				
F	1	10	101	11.3	17.5	40" FR4 (6-mil trace) or 9m (24 AWG) PCIe cable			
		10	110	12.3	18.6				
0	1	10	111	12.8	19.8	50" FR4 (6-mil trace) or 10m (24 AWG) PCIe cable			
	F=	F=Float (don't drive pin, each float pin has an internal 50K Ohm resistor to VDD and GND), 1=High, 0=Low							

TABLE 3. Equalization Settings with GST=3 for Pins or SMBus Registers

		EQ S	etting	EQ Ga	in (dB)	
EQ1	EQ0	GST	BST	1.25 GHz	2.5 GHz	Suggested Use
		[1.0]	[2.0]			
		11	000	6.4	12.2	
1	0	11	001	8.5	15.6	30" FR4 (6-mil trace) or 7m (24 AWG) PCIe cable
		11	010	10.4	18.3	
0	F	11	011	12.4	21.3	15m (24 AWG) PCIe cable
		11	100	15.2	25.0	
1	F	11	101	18.1	27.2	> 15m (24 AWG) PCIe cable
		11	110	19.6	28.8	
		11	111	20.2	30.7	
	F=	=Float (o	don't driv	e pin, each floa	t pin has an inte	rnal 50K Ohm resistor to VDD and GND), 1=High, 0=Low

The De-Emphasis level must be set when in SMBus mode. See *SMBus TRANSACTIONS* section and *Table 9* for specific De-Emphasis values.

TABLE 4. De-Emphasis Input Select Pins for A and B ports (3–Level Input)

RATE	DEM1	DEM0	Typical De- Emphasis Level	Typical DE Pulse Width	Typical VOD	Suggested Use
0/F	0	0	0dB	0ps	1000mV	
0/F	0	1	-3.5dB	400ps	1000mV	8 inches FR4 (6-mil trace) or less than 1 meter (28 AWG) PCIe cable
0/F	1	0	-6dB	400ps	1000mV	
0/F	1	1	-6dB	400ps enhanced	1000mV	15 inches FR4 (6-mil trace)
0/F	0	F	-9dB	400ps enhanced	1000mV	
0/F	1	F	-12dB	400ps enhanced	1000mV	
0/F	F	0	-9dB	400ps enhanced	1200mV	30 inches FR4 (6-mil trace)
0/F	F	1	-12dB	400ps enhanced	1400mV	40 inches FR4 (6-mil trace)
0/F	F	F	Reserved, don't use			
1/F	0	0	0dB	0ps	1000mV	
1/F	0	1	-3.5dB	200ps	1000mV	
1/F	1	0	-6dB	200ps	1000mV	
1/F	1	1	-6dB	200ps enhanced	1000mV	10 inches FR4 (6-mil trace)
1/F	0	F	-9dB	200ps enhanced	1000mV	
1/F	1	F	-12dB	200ps enhanced	1000mV	
1/F	F	0	-9dB	200ps enhanced	1200mV	20 inches FR4 (6-mil trace)
1/F	F	1	-12dB	200ps enhanced	1400mV	30 inches FR4 (6-mil trace)
1/F	F	F	Reserved, don't use			

F=Float (don't drive pin - (each float pin has an internal 50K Ohm resistor to VDD and GND). Enhanced DE Pulse width provides additional de-emphasis on second bit. VOD = Voltage Output Differential amplitude. When RATE is floated (F=Auto Rate Detection Active) DE Level and Pulse Width settings follow detected RATE. RATE=0 is 2.5GBps, RATE=1 is 5 GBps

TABLE 5. Idle Control (3-Level Input)

TXIDLEA/B	Function
0	This state is for lossy media, dedicated Idle threshold detect circuit disabled, output follows input based
	on EQ settings. Idle state not guaranteed.
Float	Float enables automatic idle detection. Idle on the input is passed to the output. This is the
	recommended default state. Output driven to idle if diff input signal less than value set by SD_I H pin.
1	Manual override, output forced to Idle. Diff inputs are ignored.

TABLE 6. Receiver Electrical Idle Detect Threshold Adjust (Analog input - Connect Resistor to GND or Float)

SD_TH resistor value (Ω) (connect from pin to GND)	Typical Receiver Electrical Idle Detect Threshold (DIFF p-p)			
Float (no resistor required)	130mV (default condition)			
0	225mV			
80K	20mV			
SD_TH resistor value can be set from 0 through 80K Ohms to achieve desired idle detect threshold, see <i>Figure 1</i> . 8K Ohm is				





FIGURE 1. Typical Idle threshold vs SD_TH resistor value

Receiver Detection

The Rx detection process is a feature that can set the number of active channels on the DS50PCI402. By sensing the presence of a valid PCIe load on the output, the channel can be automatically enabled for operation. This allows the DS50P-CI402 to configure inself to the proper lane width, whether it is a 4-lane, 2-lane, or 1-lane PCIe link.

Automatic Rx Detection is enabled by a combination of PRSNT# and ENRXDET inputs. When these inputs are set

low, Automatic Rx Detection is enabled, cycling of the PRSNT# pin will reset the Rx detection circuitry, initiating a new receiver detection sequence. Pulling the ENRXDET input to logic 1, allows for manual control of the input termination.

The table below summarizes control pin and receiver detect operation for the DS50PCI402.

PRSNT#	ENRXDET	RXDETA/B	Input Termination	Termination sensed on Output	Function
0	0	0	>50KΩ to VDD	Hi - Z	Automatic RXDET: Rx detection state
			50Ω	PCIe Input	machine enabled. Outputs will test for the
					presence of a receiver input every 12 msec
					until detection occurs. Input termination
					remains >50 K Ω to VDD until receiver is
					detected. Once receiver is detected, input
0	0			11: 7	Impedance to VDD is 5002.
0	0	I	$>50K\Omega$ to VDD	HI - Z	Automatic RXDEI: RX detection state
			50Ω	PCIe Input	presence of a receiver input every 12 msec
					for 600 msec and then stop. Input
					termination remains >50K Ω to VDD until
					receiver is detected. Once receiver is
					detected, input impedance to VDD is 50Ω .
					Restart detection if RXDETA/B is pulsed
					low-high.
0	1	0	>50KΩ to VDD	X	Manual RXDET: Rx detection state machine
					disabled. Input termination >50 K Ω .
					Associated output channels in low power
					idle mode.
0	1	1	50Ω	X	Manual RXDEI: Rx detection state machine
					disabled. Input termination 500. Associated
	X	N N		N N	output channels set to active.
	X	X	>50 K Ω to VDD	X	Power down mode: input termination
					in nower saving mode PRSNT# should be
					held high for a minimum of 5 us to ensure
					complete analog power down. The
					Automatic RXDET functionality will be re-
					initialized on the falling edge of PRSNT#.

TABLE 7. Receiver Detect Pins for A and B ports (LVCMOS inputs)

RX Detect: Range of Operation

The Rx detection process used in the DS50PCI402 is designed to be fully compliant with the PCIe 2.0 base specification. The receiver detection circuitry will accurately detect a receiver when both conditions listed below are true:

- DS50PCI402 within Recommended Operating Range for Temperature and Supply Voltage
- For receiver Z_{RX-DC} = 40 (min) to 60 (max) Ohms

Note: To ensure robust system operation, the DS50PCI402 will only signal a valid receiver detection if both halves of the differential output pair detect a proper 40 - 60 Ohm receiver impedance. If the receiver detection circuitry senses a load impedance greater than $Z_{\text{RX-DC}}$ on either trace of a differential pair, it will be interpreted as no termination load present (i.e. the corresponding DS50PCI402 input termination will remain High-Z).

Manual Control Of RXDETA/B In A PCIe Environment

In some cases manual control of RXDETA/B may be desirable. In order for upstream and downstream PCIe subsystems to communicate in a cabling environment, the PCIe specification includes several auxiliary or sideband signals to manage system-level functionality or implementation. Similar methods are used in backplane applications, but the exact implementation falls outside the PCIe standard. Initial communication from the downstream subsystem to the upstream subsystem is done with the CPRSNT# auxiliary signal. The CPRSNT# signal is asserted Low by the downstream componentry after the "Power Good" condition has been established. This mechanism allows for the upstream subsystem to determine whether the power is good within the downstream subsystem, enable the reference clock, and initiate the Link Training Sequence.



FIGURE 2. Typical PCIe System Timing

The signals shown in the graphic could be easily replicated within the downstream subsystem and used to externally control the common mode input termination impedance on the DS50PCI402. Often an onboard microcontroller will be used to handle events like power-up, power-down, power saving modes, and hot insertion. The microcontroller would use the

same information to determine when to enable and disable the DS50PCI402 input termination. In applications that require SMBus control, the microcontroller could also delay any response to the upstream subsystem to allow sufficient time to correctly program the DS50PCI402 and other devices on the board.

Absolute Maximum Ratings (Note 2)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Supply Voltage (VDD)	-0.5V to +3.0V
LVCMOS Input/Output Voltage	-0.5V to +4.0V
CML Input Voltage	-0.5V to (VDD+0.5V)
CML Input Current	-30 to +30 mA
LPDS Output Voltage	-0.5V to (VDD+0.5V)
Analog (SD_TH)	-0.5V to (VDD+0.5V)
Junction Temperature	+125°C
Storage Temperature	-40°C to +125°C
Lead Temperature Range	
Maximum Package Power Dissi	pation at 25°C
SQA54A Package	4.21 W
Derate SQA54A Package	52.6mW/°C above +25°C
ESD Rating	
HBM, STD - JESD22-A114C	≥6 kV

MM, STD - JESD22-A115-A CDM, STD - JESD22-C101-C	≥250 V ≥1250 V			
Thermal Resistance				
θ _{JC}	11.5°C/W			
θ_{JA} , No Airflow, 4 layer JEDEC	19.1°C/W			
For soldering specifications: see product folder at				

www.national.com

www.national.com/ms/MS/MS-SOLDERING.pdf

Recommended Operating Conditions

	Min	Тур	Max	Units
Supply Voltage				
V _{DD} to GND	2.375	2.5	2.625	V
Ambient Temperature	-10	25	+85	°C
SMBus (SDA, SCL)			3.6	V
Supply Noise Tolerance			100	mV
up to 50Mhz (<i>Note 5</i>)				рр

Electrical Characteristics

Over recommended operating supply and temperature ranges with default register settings unless other specified.

(Note 3, Note 4)						
Symbol	Parameter	Conditions	Min	Тур	Max	Units
POWER (Note 13)		•	·			
PD	Power Dissipation	EQX=Float, DEX=0, VOD=1Vpp ,PRSNT=0		800	1000	mW
		PRSNT=1, ENSMB=0		4	8	mW
LVCMOS / LVTTL D	C SPECIFICATIONS					
V _{IH}	High Level Input Voltage	(Note 15)	2		3.6	V
V _{IL}	Low Level Input Voltage	(Note 15)	0		0.8	V
V _{OH}	High Level Output Voltage	SMBUS open drain V _{OH} set by pullup Resistor				V
V _{OL}	Low Level Output Voltage	I _{OL} = 4mA			0.4	V
I _{IH}	Input High Current	V _{IN} = 3.6V , LVCMOS	-15		+15	
		V _{IN} = 3.6V , w/ FLOAT,PULLDOWN input	-15		+120	μΑ
I _{IL}	Input Low Current	V _{IN} = 0V	-15		+15	
		V _{IN} = 0V, w/FLOAT input	-80		+15	μA

Symbol	Parameter	Conditions	Min	Тур	Мах	Units
CML RECEIVER INPUT	S (IN_n+, IN_n-)					
RL _{RX-DIFF}	Rx package plus Si	0.05GHz – 1.25GHz (<i>Note 6</i>)		-21		dB
	differential return loss	1.25GHz – 2.5GHz (<i>Note 6</i>)		-20		
RL _{RX-CM}	Common mode Rx return loss	0.05GHz - 2.5GHz (<i>Note 6</i>)		-11.5		dB
Z _{RX-DC}	Rx DC common mode impedance	Tested at VDD=0	40	50	60	Ω
Z _{RX-DIFF-DC}	Rx DC differential impedance	Tested at VDD=0	85	100	115	Ω
V _{RX-DIFF-DC}	Differential Rx peak to peak voltage	Tested at DC, TXIDLEx=0	0.10		1.2	V
Z _{RX-HIGH-IMP-DC} -POS	DC Input CM impedance for V>0	Vin = 0 to 200 mV, RXDETA/B = 0, ENSMB = 0, VDD=2.625	50			ΚΩ
V _{RX-IDLE-DET-DIFF-PP}	Electrical Idle detect threshold	SD_TH = float, see <i>Table 6</i> , (<i>Note 16</i>)	40		175	mV _{P-P}
LPDS OUTPUTS (OUT_		· · · · · · · · · · · · · · · · · · ·				
V _{TX-DIFF-PP}	Output Voltage Swing	Differential measurement with OUT_n+ and OUT_n- terminated by 50Ω to GND AC-Coupled, <i>Figure 4</i> , (<i>Note 13</i>)	800	1000	1200	mV _{P-P}
V _{OCM}	Output Common-Mode Voltage	Single-ended measurement DC- Coupled with 50Ω termination, (<i>Note 3</i>)		V _{DD} - 1.4		v
V _{TX-DE-RATIO-3.5}	Tx de-emphasis level ratio	VOD = 1000 mV, DEM1 = GND, DEM0 = VDD, (<i>Note 3</i>), (<i>Note 12</i>)		3.5		dB
V _{TX-DE-RATIO-6}	Tx de-emphasis level ratio	VOD = 1000 mV, DEM1 = VDD, DEM0 = GND, (<i>Note 3</i>), (<i>Note 12</i>)		6		dB
T _{TX-HE-D.I-DD}	Tx Dj > 1.5 Mhz	(Note 7)			0.15	UI
	Tx RMS jitter < 1.5Mhz	(Note 7)			3.0	ps RMS
T _{TX-RISE-FALL}	Transmitter Rise/ Fall Time	20% to 80% of differential output voltage, <i>Figure 3</i> (<i>Note 3</i> , <i>Note 8</i>)	50	67		ps
T _{RF-MISMATCH}	Tx rise/fall mismatch	20% to 80% of differential output voltage (<i>Note 3</i> , <i>Note 8</i>)		0.01	0.1	UI
RL _{TX-DIFF}	Differential Output	0.05- 1.25 Ghz, See <i>Figure 6</i>		-23		dB
	Return Loss	1.25- 2.5 Ghz, See Figure 6		-20		dB
RL _{TX-CM}	Common Mode Return Loss	0.05- 2.5 Ghz, See Figure 6		-11		dB
Z _{TX-DIFF-DC}	DC differential Tx impedance			100		Ω
V _{TX-CM-AC-PP}	Tx AC common mode voltage				100	mVpp
I _{TX-SHORT}	transmitter short circuit current limit	Total current transmitter can supply when shorted to VDD or GND			90	mA
V _{TX-CM-DC} - ACTIVE-IDLE- DELTA	Absolute Delta of DC Common Mode Voltage during L0 and electrical Idle				40	mV

Symbol	Parameter	Conditions	Min	Тур	Max	Units
V _{TX-CM-DC} - LINE-DELTA	Absolute Delta of DC Common Mode Voltage between Tx+ and Tx-				25	mV
T _{TX-IDLE-SET-TO} -IDLE	Max time to transition to valid diff signaling after leaving Electrical Idle	VIN = 800 mVp-p, 5 Gbps, <i>Figure 5</i>		6.5	9.5	nS
T _{TX-IDLE-TO} -DIFF-DATA	Max time to transition to valid diff signaling after leaving Electrical Idle	VIN = 800 mVp-p, 5 Gbps, <i>Figure 5</i>		5.5	8	nS
T _{PDEQ}	Differential Propagation Delay	EQ = 11, +4.0 dB @ 2.5 GHz , <i>Figure 4</i> (<i>Note 10</i>)	150	200	250	ps
T _{PD}	Differential Propagation Delay	EQ = FF, Equalizer Bypass, <i>Figure 4</i> (<i>Note 10, Note 9</i>)	120	170	220	ps
T _{LSK}	Lane to Lane Skew in a Single Part	T _A = 25C,V _{DD} = 2.5V (<i>Note 8, Note 9</i>)			27	ps
T _{PPSK}	Part to Part Propagation Delay Skew	T _A = 25C,V _{DD} = 2.5V			35	ps
EQUALIZATION						
DJE1	Residual Deterministic Jitter at 5 Gbps	42" of 5 mil stripline FR4, EQ1,0=F,1; K28.5 pattern, DEMx=0, Tx Launch Amplitude 1.0 Vp-p, SD_TH=F. (<i>Note 3</i> , <i>Note 11</i>)		0.02	0.09	UI _{P-P}
DJE2	Residual Deterministic Jitter at 2.5 Gbps	42" of 5 mil stripline FR4, EQ1,0=F,1; K28.5 pattern, DEMx=0, Tx Launch Amplitude 1.0 Vp-p, SD_TH=F. (<i>Note 3</i> , <i>Note 11</i>)		0.02	0.04	UI _{P-P}
DJE3	Residual Deterministic Jitter at 5 Gbps	7 meters of 24 AWG PCIe cable, EQ1,0=1,0; K28.5 pattern, DEMx=0, Tx Launch Amplitude 1.0 Vp-p, SD_TH=F. (<i>Note 3</i> , <i>Note 11</i>)		0.02	0.11	UI _{P-P}
DJE4	Residual Deterministic Jitter at 2.5 Gbps	7 meters of 24 AWG PCIe cable, EQ1,0=1,0; K28.5 pattern, DEMx=0, Tx Launch Amplitude 1.0 Vp-p, SD_TH=F. (<i>Note 3</i> , <i>Note 11</i>)		0.03	0.07	UI _{P-P}
RJ	Random Jitter	Tx Launch Amplitude 1.0 Vp-p, SD_TH=F, Repeating 1100b (D24.3) pattern. (<i>Note 3</i>)		<0.5		psrms

Symbol	Parameter	Conditions	Min	Тур	Max	Units
DE-EMPHASIS		•		•		5
DJD1	Residual Deterministic Jitter at 5 Gbps	28" of 5 mil stripline FR4, EQ1,0=F,F; K28.5 pattern, DEM1,0=F,1; Tx Launch Amplitude 1.0 Vp-p, SD_TH=F. (<i>Note 3, Note 11</i>)		0.02	0.09	UI _{P-P}
DJD2	Residual Deterministic Jitter at 2.5 Gbps	28" of 5 mil microstrip FR4, EQ1,0=F,F; K28.5 pattern, DEM1,0=F,0; Tx Launch Amplitude 1.0 Vp-p, SD_TH=F. (<i>Note 3, Note 11</i>)		0.03	0.05	UI _{P-P}
DJD3	Residual Deterministic Jitter at 5 Gbps	7 meters of 24 AWG PCIe cable, EQ1,0=F,F; K28.5 pattern, DEM1,0=F,1; Tx Launch Amplitude 1.0 Vp-p, SD_TH=F. (<i>Note 3, Note 11</i>)		0.03	0.13	UI _{P-P}
DJD4	Residual Deterministic Jitter at 2.5 Gbps	7 meters of 24 AWG PCIe cable, EQ1,0=F,F; K28.5 pattern, DEM1,0=F,0; Tx Launch Amplitude 1.0 Vp-p, SD_TH=F. (<i>Note 3, Note 11</i>)		0.04	0.06	UI _{P-P}

Note 2: "Absolute Maximum Ratings" indicate limits beyond which damage to the device may occur, including inoperability and degradation of device reliability and/or performance. Functional operation of the device and/or non-degradation at the Absolute Maximum Ratings or other conditions beyond those indicated in the Recommended Operating Conditions is not implied. The Recommended Operating Conditions indicate conditions at which the device is functional and the device should not be operated beyond such conditions. Absolute Maximum Numbers are guaranteed for a junction temperature range of -40°C to +125°C. Models are validated to Maximum Operating Voltages only.

Note 3: Typical values represent most likely parametric norms at V_{DD} = 2.5V, T_A = 25°C, and at the Recommended Operation Conditions at the time of product characterization and are not guaranteed.

Note 4: The Electrical Characteristics tables list guaranteed specifications under the listed Recommended Operating Conditions except as otherwise modified or specified by the Electrical Characteristics Conditions and/or Notes. Typical specifications are estimations only and are not guaranteed.

Note 5: Allowed supply noise $(mV_{P-P} \text{ sine wave})$ under typical conditions.

Note 6: Input Return Loss also uses the setup shown in *Figure 6*. The blocking / biasing circuit is replaced with a simple AC coupling capacitor for each input to emulate a typical PCIe application.

Note 7: PCIe 2.0 transmit jitter specifications - actual device jitter is much less. Actual device Rj and Dj has been characterized and specified with test loads outlined in the EQUALIZATION and DE-EMPHASIS sections of the Electrical Characteristics table.

Note 8: Guaranteed by device characterization

Note 9: Propagation Delay measurements for Part to Part skew are all based on devices operating under indentical temperature and supply voltage conditions. **Note 10:** Propagation Delay measurements will change slightly based on the level of EQ selected. EQ Bypass will result in the shortest propagation delays.

Note 11: Residual DJ measurements subtract out deterministic jitter present at the generator outputs. For 2.5 Gbps generator Dj = 0.0275 UI and for 5.0 Gbps generator Dj = 0.035 UI.

Note 12: Measured with a repeating K28.5 pattern at a data rate of 2.5 Gbps and 5.0 Gbps.

Note 13: Measured with DEM Select pins configured for 1000mV VOD, see De-emphasis table.

Note 14: Measured at default SD_TH settings

Note 15: Input edge rate for LVCMOS/FLOAT inputs must be 50ns minimum from 10-90%.

Note 16: Measured at package pins of receiver. Less than 40mV is IDLE, greater than 175mV is ACTIVE. SD_TH pin connected with resistor to GND overrides this default setting.

Electrical Characteristics — Serial Management Bus Interface

Over recommended operating supply and temperature ranges unless other specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Units
SERIAL BUS	INTERFACE DC SPECIFICATIONS				1	. <u> </u>
V _{IL}	Data, Clock Input Low Voltage				0.8	V
V _{IH}	Data, Clock Input High Voltage		2.1		3.6	V
I _{PULLUP}	Current Through Pull-Up Resistor or Current Source	High Power Specification	4			mA
V _{DD}	Nominal Bus Voltage		2.375		3.6	V
I _{LEAK-Bus}	Input Leakage Per Bus Segment	(Note 17)	-200		+200	μA
I _{LEAK-Pin}	Input Leakage Per Device Pin			-15		μA
CI	Capacitance for SDA and SCL	(Note 17, Note 18)			10	pF
R _{TERM}	External Termination Resistance pull to V_{DD} = 2.5V ± 5% OR 3.3V ±	Pullup V _{DD} = 3.3V, (<i>Note 17, Note 18, Note 19</i>)		2000		Ω
	10%	Pullup V _{DD} = 2.5V, (<i>Note 17, Note 18, Note 19</i>)		1000		Ω
SERIAL BUS	INTERFACE TIMING SPECIFICATI	ONS. See Figure 7	•		•	
FSMB	Bus Operating Frequency	(Note 20)	10		100	kHz
TBUF	Bus Free Time Between Stop and Start Condition		4.7			μs
THD:STA	Hold time after (Repeated) Start Condition. After this period, the first clock is generated.	At I _{PULLUP} , Max	4.0			μs
TSU:STA	Repeated Start Condition Setup Time		4.7			μs
TSU:STO	Stop Condition Setup Time		4.0			μs
THD:DAT	Data Hold Time		300			ns
TSU:DAT	Data Setup Time		250			ns
T _{TIMEOUT}	Detect Clock Low Timeout	(Note 20)	25		35	ms
T _{LOW}	Clock Low Period		4.7			μs
T _{HIGH}	Clock High Period	(Note 20)	4.0		50	μs
T _{LOW} :SEXT	Cumulative Clock Low Extend Time (Slave Device)	(Note 20)			2	ms
t _F	Clock/Data Fall Time	(Note 20)			300	ns
t _R	Clock/Data Rise Time	(Note 20)			1000	ns
t _{POR}	Time in which a device must be operational after power-on reset	(Note 20)			500	ms

Note 17: Recommended value. Parameter not tested in production.

Note 18: Recommended maximum capacitance load per bus segment is 400pF.

Note 19: Maximum termination voltage should be identical to the device supply voltage.

Note 20: Compliant to SMBus 2.0 physical layer specification. See System Management Bus (SMBus) Specification Version 2.0, section 3.1.1 SMBus common AC specifications for details.

Timing Diagrams



FIGURE 3. CML Output Transition Times



FIGURE 4. Propagation Delay Timing Diagram





Supply Iconnect/PC Biasing/blocking Circuit Rt + 2Rl = 98Ω ╢ Gnd 2.5V RI Bias T PCIe EVK board OUT+ Rt Biasing/ CSA8000B w/TDR module blocking PCI402 Bias T RI OUT-╢ 30107354 FIGURE 6. Input and Output Return Loss Setup tLOW t_R – ^tHIGH SCL t_{BUF} tHD:STA tHD:DAT ▶|← - t_F tSU:STA _ • tsu:sto ← tsu:dat SDA SP st¦ SP ST 30107394 FIGURE 7. SMBus Timing Parameters

System Management Bus (SMBus) and Configuration Registers

The System Management Bus interface is compatible to SM-Bus 2.0 physical layer specification. ENSMB must be pulled high to enable SMBus mode and allow access to the configuration registers.

The DS50PCI402 has the AD[3:0] inputs in SMBus mode. These pins are the user set SMBus slave address inputs. The AD[3:0] pins have internal pull-down. When left floating or pulled low the AD[3:0] = 0000'b, the device default address byte is A0'h. Based on the SMBus 2.0 specification, the DS50PCI402 has a 7-bit slave address of 1010000'b. The LSB is set to 0'b (for a WRITE), thus the 8-bit value is 1010 0000'b or A0'h. The device address byte can be set with the use of the AD[3:0] inputs. Below are some examples.

AD[3:0] = 0001'b, the device address byte is A2'h

AD[3:0] = 0010'b, the device address byte is A4'h

AD[3:0] = 0100'b, the device address byte is A8'h

AD[3:0] = 1000'b, the device address byte is B0'h

The SDA, SCL pins are 3.3V tolerant, but are not 5V tolerant. External pull-up resistor is required on the SDA. The resistor value can be from 1 k Ω to 5 k Ω depending on the voltage, loading and speed. The SCL may also require an external pull-up resistor and it depends on the Host that drives the bus.

TRANSFER OF DATA VIA THE SMBus

During normal operation the data on SDA must be stable during the time when SCL is High.

There are three unique states for the SMBus:

START: A High-to-Low transition on SDA while SCL is High indicates a message START condition.

STOP: A Low-to-High transition on SDA while SCL is High indicates a message STOP condition.

IDLE: If SCL and SDA are both High for a time exceeding t_{BUF} from the last detected STOP condition or if they are High for a total exceeding the maximum specification for t_{HIGH} then the bus will transfer to the IDLE state.

SMBus TRANSACTIONS

The device supports WRITE and READ transactions. See Register Description table for register address, type (Read/ Write, Read Only), default value and function information.

When SMBus is enabled, the DS50PCI402 **must use one of the following De-emphasis settings** (*Table 8*). The driver de-emphasis value is set on a per channel basis using 8 different registers. Each register (0x11, 0x18, 0x1F, 0x26, 0x2E, 0x35, 0x3C, 0x43) requires one of the following De-emphasis settings when in SMBus mode. See *Table 4* for suggested DE settings at 2.5 and 5.0 Gbps operation.

TABLE 8. De-Emphasis Register Settings (must write one of the following when in SMBus mode)

De-Emphasis Value	Register Setting
0.0 dB	0x01
-3.5 dB	0xE8
-6 dB	0x88
-9 dB	0x90
-12 dB	0xA0

WRITING A REGISTER

To write a register, the following protocol is used (see SMBus 2.0 specification).

- 1. The Host drives a START condition, the 7-bit SMBus address, and a "0" indicating a WRITE.
- 2. The Device (Slave) drives the ACK bit ("0").
- 3. The Host drives the 8-bit Register Address.
- 4. The Device drives an ACK bit ("0").
- 5. The Host drive the 8-bit data byte.
- 6. The Device drives an ACK bit ("0").
- 7. The Host drives a STOP condition.

The WRITE transaction is completed, the bus goes IDLE and communication with other SMBus devices may now occur.

READING A REGISTER

To read a register, the following protocol is used (see SMBus 2.0 specification).

- 1. The Host drives a START condition, the 7-bit SMBus address, and a "0" indicating a WRITE.
- 2. The Device (Slave) drives the ACK bit ("0").
- 3. The Host drives the 8-bit Register Address.
- 4. The Device drives an ACK bit ("0").
- 5. The Host drives a START condition.
- 6. The Host drives the 7-bit SMBus Address, and a "1" indicating a READ.
- 7. The Device drives an ACK bit "0".

- 8. The Device drives the 8-bit data value (register contents).
- 9. The Host drives a NACK bit "1"indicating end of the READ transfer.
- 10. The Host drives a STOP condition.

The READ transaction is completed, the bus goes IDLE and communication with other SMBus devices may now occur. Please see SMBus Register Map Table for more information.

SMBus REGISTER WRITES:

The DS50PCl402 outputs will NOT be PCle compliant with the SMBus registers enabled (ENSMB = 1) until the VOD levels have been set. Below is an example to configure the VOD level to a PCle compliant amplitude and adjust the DE and EQ signal conditioning to work with a 7m PCle cable interconnect on the input B-side / output A-side of the device

- 1. Reset the SMBus registers to default values: Write 01'h to address 0x00.
- Set VOD = 1.0V for all channels (OA[3:0] and OB[3:0]): Write 0F'h to address 0x10, 0x17, 0x1E, 0x25, 0x2D, 0x34, 0x3B, 0x42.
- Set equalization to external pin level EQ[1:0] = 10 (~15.5 dB at 2.5 GHz) for all channels (IB[3:0]):
 Write 39'h to address 0x0F, 0x16, 0x1D, 0x24.
- Set de-emphasis to DE[1:0] = F1 or -12 dB enhanced for all A channels (OA[3:0]):
 Write A0'h to address 0x2E, 0x35, 0x3C, 0x43.

IDLE AND RATE DETECTION TO EXTERNAL PINS

The functions of IDLE and RATE detection to external pins for monitoring can be supported in SMBus mode. The external GPIO pins of 19, 20, 46 and 47 will be changed and they will serve as outputs for IDLE and RATE detect signals.

The following external pins should be set to auto detection:

RATE = F (FLOAT) – auto RATE detect enabled

TXIDLEA/B = F (FLOAT) - auto IDLE detect enabled

There are 4 GPIO pins that can be configured as outputs with $reg_4E[0]$.

To disable the external SMBus address pins, so pin 46 and 47 can be used as outputs:

Write 01'h to address 0x4E.

Care must be taken to ensure that only the desired status block is enabled and attached to the external pin as the status blocks can be OR'ed together internally. Register bits reg_47 [5:4] and bits reg_4C[7:6] are used to enable each of the status block outputs to the external pins. The channel status blocks can be internally OR'ed together to monitor more than one channel at a time. This allows more information to be presented on the status outputs and later if desired, a diagnosis of the channel identity can be made with additional SMBus writes to register bits reg_47[5:4] and bits reg_4C[7:6].

Below are examples to configure the device and bring the internal IDLE and RATE status to pins 19, 20, 46, 47. To monitor the IDLE detect with two channels ORed (CH0 with CH2, CH1 with CH3, CH4 with CH6, CH5 with CH7):

Write 32'h to address 0x47.

The following IDLE status should be observable on the external pins:

pin 19 - CH0 with CH2,

pin 20 - CH1 with CH3,

pin 46 - CH4 with CH6,

pin 47 - CH5 with CH7.

Pin = HIGH (VDD) means IDLE is detected (no signal present).

Pin = LOW (GND) means ACTIVE (data signal present). To monitor the RATE detect with two channels ORed (CH0 with CH2, CH1 with CH3, CH4 with CH6, CH5 with CH7):

Write C0'h to address 0x4C.

The following RATE status should be observable on the external pins:

pin 19 - CH0 with CH2,

pin 20 - CH1 with CH3,

pin 46 - CH4 with CH6,

pin 47 - CH5 with CH7.

Pin = HIGH (VDD) means high data rate is detected (6 Gbps). Pin = LOW (GND) means low rate is detected (3 Gbps).

	TABLE 9. SMBus Register Map								
Address	Register Name	Bit (s)	Field	Туре	Defaul t	Description			
0x00	Reset	7:1	Reserved	R/W	0x00	Set bits to 0.			
		0	Reset	1		SMBus Reset			
						1: Reset registers to default value			
0x01	PWDN Channels	7:0	PWDN CHx	R/W	0x00	Power Down per Channel			
						[7]: CHA_3			
						[6]: CHA_2			
						[5]: CHA_1			
						[4]: CHA_0			
						[3]: CHB_3			
						[2]: CHB_2			
						[1]: CHB_1			
						[0]: CHB_0			
						00'h = all channels enabled			
						FF'h = all channels disabled			
0x02	PWDN Control	7:1	Reserved	R/W	0x00	Set bits to 0.			
		0	Override PWDN			0: Allow PWDN pin control			
						1: Block PWDN pin control			
0x08	Pin Control Override	7:5	Reserved	R/W	0x00	Set bits to 0.			
		4	Override IDLE	1		0: Allow IDLE pin control			
						1: Block IDLE pin control			
		3	Reserved	1		Set bit to 0.			
		2	Override RATE	1		0: Allow RATE pin control			
						1: Block RATE pin control			
		1:0	Reserved]		Set bits to 0.			

0x0E	CH0 - CHB0	7:6	Reserved	R/W	0x00	Set bits to 0.
	IDLE RATE Select	5	IDLE auto			0: Allow IDLE_sel control in Bit 4
						1: Automatic IDLE detect
		4	IDLE select			0: Output is ON (SD is disabled)
						1: Output is muted (electrical idle)
		3:2	Reserved			Set bits to 0.
		1	BATE auto	-		0: Allow BATE sel control in Bit 0
						1: Automatic RATE detect
		0	BATE select	-		0: 2.5 Gbps
		-				1: 5.0 Gbps
0x0F	СН0 - СНВ0	7:6	Reserved	R/W	0x20	Set bits to 0.
	EQ Control	5:0	CH0 IB0 EQ			IB0 EQ Control - total of 24 levels
						(3 gain stages with 8 settings)
						[5]: Enable EQ
						[4:3]: Gain Stage Control
						[2:0]: Boost Level Control
						Pin [EQ1 EQ0] = Register [EN] [GST] [BST] = Hex
						Value
						FF = 100000 = 20'h = Bypass (Default)
						11 = 101010 = 2A'h
						00 = 110000 = 30'h
						F0 = 110010 = 32'h
						10 = 111001 = 39'h
						F1 = 110101 = 35'h
						01 = 110111 = 37'h
						0F = 111011 = 3B'h
				_		1F = 111101 = 3D'h
0x10	CH0 - CHB0	7	Reserved	R/W	0x03	Set bit to 0.
	VOD Control	5:0	CH0 OB0 VOD			OB0 VOD Control
						03'h = 600 mV (Default)
						07'h = 800 mV
						0F'h = 1000 mV
				_		1F'h = 1200 mV
0x11	CH0 - CHB0	7:0	CH0 OB0 DEM	R/W	0x03	OB0 DEM Control
	DE Control					[7]: DEM TYPE (Compatibility = 0 / Enhanced = 1)
						[6:0]: DEM Level Control
						Pin [DEM1 DEM0] = Register [TYPE] [Level
						Control] = Hex Value
						00 = 00000001 = 01 h = 0.0 dB
						01 = 11101000 = E8'h = -3.5 dB
						$11 = 10001000 = 88^{\circ}h = -6.0 \text{ dB}$
						UF = UU UUUU = 90'N = -9.0 dB
						$ \Gamma = 1010000 = A0 \Pi = -12.0 \text{ dB}$
						F = 10010000 = 3011 = -9.0 dB F = 10100000 = 0.0 b = -12.0 dB
						FE = 11000000 = C0'h = Reserved
0x12	CH0 - CHB0	7.4	Reserved	B/W	0x00	Set hits to 0
UXIZ		1.4				
		3:0				De-assert = $[3:2]$, assert = $[1:0]$
						00 = 110 mV, 70 mV (Default)
						10 = 170 mV 120 mV

0x15	CH1 - CHB1	7:6	Reserved	R/W	0x00	Set bits to 0.
	IDLE RATE Select	5	IDI E auto	-		0: Allow IDLE sel control in Bit 4
		ľ				1: Automatic IDLE detect
		4	IDI E select	-		0: Output is ON (SD is disabled)
		4	IDLL Select			1: Output is muted (electrical idle)
		2.2	Beconved	-		Set hits to 0
		3.2	Reserved	-		
		1	RATE auto			0: Allow RATE_sel control in Bit 0
				_		1: Automatic RATE detect
		0	RATE select			0: 2.5 Gbps
			- ·			1: 5.0 Gbps
0x16	CH1 - CHB1	7:6	Reserved	R/W	0x20	Set bits to 0.
	EQ Control	5:0	CH1 IB1 EQ			IB1 EQ Control - total of 24 levels
						(3 gain stages with 8 settings)
						[5]: Enable EQ
						[4:3]: Gain Stage Control
						[2:0]: Boost Level Control
						Pin [EQ1 EQ0] = Register [EN] [GS1] [BS1] = Hex
						FF = 100000 = 20 m = Bypass (Detault)
						11 = 101010 = 2A fi
						100 = 110010 = 3011
						F0 = 110010 = 3211 10 - 111001 - 30'b
						$F_1 = 110101 = 35$
						11 - 110101 - 3511 01 - 110111 - 37b
						OF = 111011 = 3B'b
						1F = 111101 = 3D'h
0x17	CH1 - CHB1	7	Reserved	B/W	0x03	Set bit to 0
	VOD Control	5.0				OB1 VOD Control
		0.0				03'b = 600 mV (Default)
						07'h = 800 mV
						0F'h = 1000 mV
						$1F'_{h} = 1200 \text{ mV}$
0v18	CH1 - CHB1	7.0	CH1 OB1 DEM	B/W	0x03	OB1 DEM Control
	DE Control	1.0				[7]: DEM TYPE (Compatibility = 0 / Enhanced = 1)
						[6:0]: DEM Level Control
						Pin [DEM1 DEM0] = Register [TYPE] [Level
						Control] = Hex Value
						00 = 00000001 = 01'h = 0.0 dB
						01 = 11101000 = E8'h = -3.5 dB
						11 = 10001000 = 88'h = -6.0 dB
						0F = 10010000 = 90'h = -9.0 dB
						1F = 10100000 = A0'h = -12.0 dB
						F0 = 10010000 = 90'h = -9.0 dB
						F1 = 10100000 = A0'h = -12.0 dB
						FF = 11000000 = C0'h = Reserved
0x19	CH1 - CHB1	7:4	Reserved	R/W	0x00	Set bits to 0.
	IDLE Threshold	3:0	IDLE threshold	1		De-assert = [3:2], assert = [1:0]
						00 = 110 mV, 70 mV (Default)
						01 = 150 mV, 110 mV
						10 = 170 mV, 130 mV
	1	1	1	1	1	

0x1C	CH2 - CHB2	7:6	Reserved	R/W	0x00	Set bits to 0.
	IDLE RATE Select	5	IDLE auto			0: Allow IDLE_sel control in Bit 4
						1: Automatic IDLE detect
		4	IDLE select			0: Output is ON (SD is disabled)
						1: Output is muted (electrical idle)
		3:2	Reserved			Set bits to 0.
		1	BATE auto			0: Allow BATE sel control in Bit 0
						1: Automatic RATE detect
		0	RATE select			0: 2.5 Gbps
						1: 5.0 Gbps
0x1D	CH2 - CHB2	7:6	Reserved	R/W	0x20	Set bits to 0.
	EQ Control	5:0	CH2 IB2 EQ			IB2 EQ Control - total of 24 levels
						(3 gain stages with 8 settings)
						[5]: Enable EQ
						[4:3]: Gain Stage Control
						[2:0]: Boost Level Control
						Pin [EQ1 EQ0] = Register [EN] [GST] [BST] = Hex
						Value
						FF = 100000 = 20'h = Bypass (Default)
						11 = 101010 = 2A'h
						00 = 110000 = 30'h
						F0 = 110010 = 32'h
						10 = 111001 = 39'h
						F1 = 110101 = 35'h
						01 = 110111 = 37'h
						0F = 111011 = 3B'h
			_			1F = 111101 = 3D'h
0x1E	CH2 - CHB2	7	Reserved	R/W	0x03	Set bit to 0.
	VOD Control	5:0	CH2 OB2 VOD			OB2 VOD Control
						03'h = 600 mV (Default)
						07'h = 800 mV
						0F'h = 1000 mV
						1F'h = 1200 mV
0x1F	CH2 - CHB2	7:0	CH2 OB2 DEM	R/W	0x03	OB2 DEM Control
	DE Control					[7]: DEM TYPE (Compatibility = 0 / Enhanced = 1)
						[6:0]: DEM Level Control
						00 = 00000001 = 0111 = 0.0 dB
						01 = 11101000 = E011 = -3.5 dB
						11 = 10001000 = 8811 = -0.0 dB
						1F = 1010000 = 40 h = -12.0 dB
						$F_0 = 10010000 = 90'h = -9.0 dB$
						F1 = 10100000 = A0'h = -12.0 dB
						FF = 11000000 = C0'h = Reserved
0x20	CH2 - CHB2	7:4	Reserved	R/W	0x00	Set bits to 0.
5	IDLE Threshold	3.0	IDI E threshold	-		De-assert = $[3:2]$ assert = $[1:0]$
		0.0				$00 = 110 \text{ mV} \ 70 \text{ mV} \ (\text{Default})$
						01 = 150 mV 110 mV
						10 = 170 mV, 130 mV
						11 - 190 mV 150 mV

0×23		7.6	Beconvod		0200	Sat hits to 0
0,23		7.0			0,00	
		5	IDLE auto			0: Allow IDLE_sel control in Bit 4
				4		1: Automatic IDLE detect
		4	IDLE select			0: Output is ON (SD is disabled)
				_		1: Output is muted (electrical idle)
		3:2	Reserved			Set bits to 0.
		1	RATE auto			0: Allow RATE_sel control in Bit 0
						1: Automatic RATE detect
		0	RATE select			0: 2.5 Gbps
						1: 5.0 Gbps
0x24	СНЗ - СНВЗ	7:6	Reserved	R/W	0x20	Set bits to 0.
	EQ Control	5:0	CH3 IB3 EQ	7		IB3 EQ Control - total of 24 levels
						(3 gain stages with 8 settings)
						[5]: Enable EQ
						[4:3]: Gain Stage Control
						[2:0]: Boost Level Control
						Pin [EQ1 EQ0] = Register [EN] [GST] [BST] = Hex
						Value
						FF = 100000 = 20'h = Bypass (Default)
						11 = 101010 = 2A'h
						00 = 110000 = 30'h
						F0 = 110010 = 32'h
						10 = 111001 = 39'h
						F1 = 110101 = 35'h
						01 = 110111 = 37'h
						OF = 111011 = 3B'h
						1F = 111101 = 3D'h
0x25	CH3 - CHB3	7	Reserved	B/W	0x03	Set bit to 0
0,120	VOD Control	5.0		-	0,000	OB3 VOD Control
		0.0				0.3'h = 600 mV (Default)
						07'h = 800 mV
						OF'h = 1000 mV
						1F'h = 1200 mV
0x26	CH3 - CHB3	7.0		B/W	0x03	
0,20	DE Control	1.0	ONO OBO DEM			[7]: DEM TYPE (Compatibility $= 0$ / Enhanced $= 1$)
						[6:0]: DEM Level Control
						Pin [DEM1 DEM0] - Begister [TYPE] [Level
						Controll – Hex Value
						00 = 00000001 = 01 = 0.0 dB
						01 - 11101000 - E8'h3.5 dB
						11 - 10001000 - 88'h6.0 dB
				1		AE = 10010000 = 00'h = -0.0 dB
						1E = 1010000 = 3011 = -3.0 dB
						$F_{0} = 10010000 = 00$ $F_{0} = 0.0$ dB
						$F_1 = 1010000 = 3011 = -3.0 \text{ dB}$
						FF = 11000000 = C0'h = Beserved
0x27	CH3 - CHB3	7.4	Reserved	B/W	0x00	Set bits to 0
	IDLE Threshold	3.0	IDI E threshold	-		$D_{0-assert} = [3:2]_{assert} = [1:0]$
		0.0				00 - 110 m/(70 m/(100 fm))
				1		100 = 110 mV, 70 mV (Delault) 101 = 150 mV, 110 mV
						10 - 170 mV 130 mV
						10 = 1/0 mV, 130 mV
		_				

0x2B	CH4 - CHA0	7:6	Reserved	R/W	0x00	Set bits to 0.
	IDLE RATE Select	5	IDLE auto			0: Allow IDLE_sel control in Bit 4
						1: Automatic IDLE detect
		4	IDLE select			0: Output is ON (SD is disabled)
						1: Output is muted (electrical idle)
		3:2	Reserved			Set bits to 0.
		1	RATE auto			0: Allow RATE sel control in Bit 0
						1: Automatic RATE detect
		0	RATE select			0: 2.5 Gbps
						1: 5.0 Gbps
0x2C	CH4 - CHA0	7:6	Reserved	R/W	0x20	Set bits to 0.
	EQ Control	5:0	CH4 IA0 EQ			IA0 EQ Control - total of 24 levels
						(3 gain stages with 8 settings)
						[5]: Enable EQ
						[4:3]: Gain Stage Control
						[2:0]: Boost Level Control
						Pin [EQ1 EQ0] = Register [EN] [GST] [BST] = Hex
						Value
						FF = 100000 = 20'h = Bypass (Default)
						11 = 101010 = 2A'h
						00 = 110000 = 30'h
						F0 = 110010 = 32'h
						10 = 111001 = 39'h
						F1 = 110101 = 35'h
						01 = 110111 = 37'h
						OF = 111011 = 3B'n
0x2D	CH4 - CHAU	/	Reserved	- R/W	0x03	
	VOD Control	5:0	CH4 OA0 VOD			
						$03^{\circ}h = 600 \text{ mV}$ (Default)
						07 H = 800 HV
						$1F'_h = 1200 \text{ mV}$
0225		7:0			0202	
UXZE	DE Control	1.0		U/ M	0x03	[7]: DEM TVPE (Compatibility = 0 / Enhanced = 1)
						[7]. DEM I THE (Compatibility = 07 Enhanced = 1)
						Pin [DEM1 DEM0] = Begister [TYPE] [Level
						Control] = Hex Value
						00 = 00000001 = 01'h = 0.0 dB
						01 = 11101000 = E8'h = -3.5 dB
						11 = 10001000 = 88'h = -6.0 dB
						0F = 10010000 = 90'h = -9.0 dB
						1F = 10100000 = A0'h = -12.0 dB
						F0 = 10010000 = 90'h = -9.0 dB
						F1 = 10100000 = A0'h = -12.0 dB
						FF = 11000000 = C0'h = Reserved
0x2F	CH4 - CHA0	7:4	Reserved	R/W	0x00	Set bits to 0.
	IDLE Threshold	3:0	IDLE threshold			De-assert = [3:2], assert = [1:0]
						00 = 110 mV, 70 mV (Default)
						01 = 150 mV, 110 mV
						10 = 170 mV, 130 mV
						11 = 190 mV, 150 mV

0x32	CH5 - CHA1	7:6	Reserved	R/W	0x00	Set bits to 0.
	IDLE RATE Select	5	IDLE auto	1		0: Allow IDLE_sel control in Bit 4
						1: Automatic IDLE detect
		4	IDLE select	1		0: Output is ON (SD is disabled)
						1: Output is muted (electrical idle)
		3:2	Reserved	1		Set bits to 0.
		1	RATE auto	1		0: Allow RATE sel control in Bit 0
						1: Automatic RATE detect
		0	RATE select	1		0: 2.5 Gbps
						1: 5.0 Gbps
0x33	CH5 - CHA1	7:6	Reserved	R/W	0x20	Set bits to 0.
	EQ Control	5:0	CH5 IA1 EQ	7		IA1 EQ Control - total of 24 levels
						(3 gain stages with 8 settings)
						[5]: Enable EQ
						[4:3]: Gain Stage Control
						[2:0]: Boost Level Control
						Pin [EQ0 EQ1] = Register [EN] [GST] [BST] = Hex
						Value
						FF = 100000 = 20'h = Bypass (Default)
						11 = 101010 = 2A'h
						00 = 110000 = 30'h
						F0 = 110010 = 3211 10 - 111001 - 20 th
						10 = 111001 = 3911 E1 = 110101 = 35'b
						11 - 110101 - 37'b
						OF = 111011 = 3B'h
						1F = 111101 = 3D'h
0x34	CH5 - CHA1	7	Reserved	R/W	0x03	Set bit to 0.
	VOD Control	5:0	CH5 OA1 VOD	1		OA1 VOD Control
						03'h = 600 mV (Default)
						07'h = 800 mV
						0F'h = 1000 mV
						1F'h = 1200 mV
0x35	CH5 - CHA1	7:0	CH5 OA1 DEM	R/W	0x03	OA1 DEM Control
	DE Control					[7]: DEM TYPE (Compatibility = 0 / Enhanced = 1)
						[6:0]: DEM Level Control
						Pin [DEM1 DEM0] = Register [TYPE] [Level
						Control] = Hex Value
						00 = 00000001 = 01'h = 0.0 dB
						01 = 11101000 = E8'h = -3.5 dB
						11 = 10001000 = 88'h = -6.0 dB
						0F = 10010000 = 90 $h = -9.0$ dB
						I F = 10100000 = A0 II = -12.0 dB
						$F_0 = 10010000 = 9011 = -9.0 \text{ dB}$ $F_1 = 10100000 = A0b = -12.0 \text{ dB}$
						FF = 11000000 = C0'h = Reserved
0x36	CH5 - CHA1	7:4	Reserved	R/W	0x00	Set bits to 0.
	IDLE Threshold	3:0	IDLE threshold	-		De-assert = [3:2], assert = [1:0]
						00 = 110 mV, 70 mV (Default)
						01 = 150 mV, 110 mV
						10 = 170 mV, 130 mV

0x39	CH6 - CHA2	7:6	Reserved	R/W	0x00	Set bits to 0.
	IDLE RATE Select	5	IDLE auto			0: Allow IDLE_sel control in Bit 4
						1: Automatic IDLE detect
		4	IDLE select			0: Output is ON (SD is disabled)
						1: Output is muted (electrical idle)
		3:2	Reserved			Set bits to 0.
		1	RATE auto	-		0: Allow RATE sel control in Bit 0
						1: Automatic RATE detect
		0	RATE select			0: 2.5 Gbps
						1: 5.0 Gbps
0x3A	CH6 - CHA2	7:6	Reserved	R/W	0x20	Set bits to 0.
	EQ Control	5:0	CH6 IA2 EQ	-		IA2 EQ Control - total of 24 levels
						(3 gain stages with 8 settings)
						[5]: Enable EQ
						[4:3]: Gain Stage Control
						[2:0]: Boost Level Control
						Pin [EQ1 EQ0] = Register [EN] [GST] [BST] = Hex
						Value
						FF = 100000 = 20'h = Bypass (Default)
						11 = 101010 = 2A'h
						00 = 110000 = 30'h
						F0 = 110010 = 32'h
						10 = 111001 = 39'h
						F1 = 110101 = 35'h
						01 = 110111 = 37'h
						OF = 111011 = 3B'h
0x3B	CH6 - CHA2	7	Reserved	R/W	0x03	Set bit to 0.
	VOD Control	5:0	CH6 OA2 VOD			OA2 VOD Control
						03'h = 600 mV (Default)
						0/n = 800 mV
						0F'' = 1000 mV
000		7.0		DAA	000	
0x3C	CH6 - CHA2	7:0	CH6 OA2 DEM	R/W	0x03	OA2 DEM Control
	DE Control					[7]: DEM TYPE (Compatibility = 07 Enhanced = 1)
						[0.0]. DEMI LEVELCONITOL Pin [DEM1 DEM0] - Pagistar [TYPE] [Lavel
						Controll – Hex Value
						00 - 00000001 - 01'h - 0.0 dB
						01 = 11101000 = F8'h = -3.5 dB
						11 = 10001000 = 88'h = -6.0 dB
						0F = 10010000 = 90'h = -9.0 dB
						1F = 10100000 = A0'h = -12.0 dB
						F0 = 10010000 = 90'h = -9.0 dB
						F1 = 10100000 = A0'h = -12.0 dB
						FF = 11000000 = C0'h = Reserved
0x3D	CH6 - CHA2	7:4	Reserved	R/W	0x00	Set bits to 0.
	IDLE Threshold	3:0	IDLE threshold	-1		De-assert = [3:2], assert = [1:0]
						00 = 110 mV, 70 mV (Default)
						01 = 150 mV, 110 mV
						10 = 170 mV, 130 mV
					1	11 = 190 mV. 150 mV

0x40	CH7 - CHA3	7:6	Reserved	R/W	0x00	Set bits to 0.
	IDLE RATE Select	5	IDLE auto	1		0: Allow IDLE_sel control in Bit 4
						1: Automatic IDLE detect
		4	IDLE select	1		0: Output is ON (SD is disabled)
						1: Output is muted (electrical idle)
		3:2	Reserved	7		Set bits to 0.
		1	RATE auto	1		0: Allow RATE_sel control in Bit 0
						1: Automatic RATE detect
		0	RATE select	1		0: 2.5 Gbps
						1: 5.0 Gbps
0x41	CH7 - CHA3	7:6	Reserved	R/W	0x20	Set bits to 0.
	EQ Control	5:0	CH7 IA3 EQ	7		IA3 EQ Control - total of 24 levels
						(3 gain stages with 8 settings)
						[5]: Enable EQ
						[4:3]: Gain Stage Control
						[2:0]: Boost Level Control
						Pin [EQ0 EQ1] = Register [EN] [GST] [BST] = Hex
						Value
						FF = 100000 = 20'h = Bypass (Default)
						11 = 101010 = 2A'h
						00 = 110000 = 30'h
						F0 = 110010 = 32'h
						10 = 111001 = 39'h
						F1 = 110101 = 35'h
						01 = 110111 = 37 n
						OF = 111011 = 3B'n 1E = 111101 = 2D'h
0x42		7	Beserved	B/W	0×03	
0742	VOD Control	5.0			0,00	QA3 VOD Control
		0.0				0.3'h = 600 mV (Default)
						07'h = 800 mV
						0F'h = 1000 mV
						1F'h = 1200 mV
0x43	CH7 - CHA3	7:0	CH7 OA3 DEM	R/W	0x03	OA3 DEM Control
	DE Control					[7]: DEM TYPE (Compatibility = 0 / Enhanced = 1)
						[6:0]: DEM Level Control
						Pin [DEM1 DEM0] = Register [TYPE] [Level
						Control] = Hex Value
						00 = 00000001 = 01'h = 0.0 dB
						01 = 11101000 = E8'h = -3.5 dB
						11 = 10001000 = 88'h = -6.0 dB
						0F = 10010000 = 90'h = -9.0 dB
						1F = 10100000 = A0'h = -12.0 dB
						F0 = 10010000 = 90'h = -9.0 dB
						F = 10100000 = A0'n = -12.0 dB
0×14		7.4	Booppied		0200	
0x44	IDI E Threshold	1:4				De apport = [2:0] apport = [1:0]
		3:0				De-assert = [3:2], assert = [1:0]
						00 = 110 mV, 70 mV (Default) 01 = 150 mV, 110 mV
						10 - 170 mV 130 mV
						11 - 190 mV 150 mV

	-	-	•		-		7
0x47	Global VOD Adjust	7:2	Reserved	R/W	0x02	Set bits to 0.	
		1:0	VOD Adjust			00 = -25.0%	
						01 = -12.5%	§
						10 = +0.0% (Default)	1
						11 = +12.5%	ľ

Applications Information

GENERAL RECOMMENDATIONS

The DS50PCI402 is a high performance circuit capable of delivering excellent performance. Careful attention must be paid to the details associated with high-speed design as well as providing a clean power supply. Refer to the information below and the latest version of the LVDS Owner's Manual for more detailed information on high speed design tips to address signal integrity design issues.

PCB LAYOUT CONSIDERATIONS FOR DIFFERENTIAL PAIRS

The CML inputs and LPDS outputs have been optimized to work with interconnects using a controlled differential

impedance of 85 - 100Ω . It is preferable to route differential lines exclusively on one layer of the board, particularly for the input traces. The use of vias should be avoided if possible. If vias must be used, they should be used sparingly and must be placed symmetrically for each side of a given differential pair. Whenever differential vias are used the layout must also provide for a low inductance path for the return currents as well. Route the differential signals away from other signals and noise sources on the printed circuit board. See AN-1187 for additional information on LLP packages.





The graphic shown above depicts different transmission line topologies which can be used in various combinations to achieve the optimal system performance. Impedance discontinuities at the differential via can be minimized or eliminated by increasing the swell around each hole and providing for a low inductance return current path. When the via structure is associated with thick backplane PCB, further optimization such as back drilling is often used to reduce the deterimential high frequency effects of stubs on the signal path.

POWER SUPPLY BYPASSING

Two approaches are recommended to ensure that the DS50PCI402 is provided with an adequate power supply. First, the supply (VDD) and ground (GND) pins should be

connected to power planes routed on adjacent layers of the printed circuit board. The layer thickness of the dielectric should be minimized so that the V_{DD} and GND planes create a low inductance supply with distributed capacitance. Second, careful attention to supply bypassing through the proper use of bypass capacitors is required. A 0.01 μ F bypass capacitor should be connected to each V_{DD} pin such that the capacitor is placed as close as possible to the DS50PCI402. Smaller body size capacitors can help facilitate proper component placement. Additionally, three capacitors with capacitance in the range of 2.2 μ F to 10 μ F should be incorporated in the power supply bypassing design as well. These capacitors can be either tantalum or an ultra-low ESR ceramic.

Typical Performance Eye Diagrams and Curves

DS50PCI402 Return Loss







30107351

FIGURE 10. Transmitter Return Loss Mask for 5.0 Gbps



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Notes

Notes

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PowerWise® Solutions	www.national.com/powerwise	Applications & Markets	www.national.com/solutions		
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